AiT Semiconductor Inc. BC856W_BC857W_BC858W

TRANSISTOR

PNP PLASTIC-ENCAPSULATE TRANSISTOR

DESCRIPTION

The BC856W, BC857W and BC858W are available in the SOT-323 package.

www.ait-ic.com

ORDERING INFORMATION

Package Type	Part Number		
SOT-323	BC856AW		
	BC856BW		
	BC857AW		
	BC857BW		
	BC857CW		
	BC858AW		
	BC858BW		
	BC858CW		
SPQ	3,000pcs/Reel		
AiT provides all RoHS Compliant Products			

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25^{\circ}C$, unless otherwise specified.

Parameter		Value		
V _{CBO,} Collector-Bas e Voltage	BC856W	-80 V		
	BC857W	-50 V		
	BC858W	-30 V		
V _{CEO} , Collector-Emitter Voltage	BC856W	-65 V		
	BC857W	-45 V		
	BC858W	-30 V		
V _{EBO} , Emitter-Base Voltage		-5 V		
Ic, Collector Current-Continuous		-0.1 A		
P _c , Collector Power Dissipation		150 mW		
T _J , Junction Temperature		150 °C		
T _{stg,} Storage Temperature		-65 ~ +150 °C		

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

FEATURE

- Low current (max. -100 mA)
- Low voltage (max. -65 V)

APPLICATION

- Ideally suited for automatic insertion.
- For switching and AF amplifier application.

PIN DESCRIPTION



PIN#	DESCRIPTION		
1	Base		
2	Emitter		
3	Collector		



ELECTRICAL CHARACTERISTICS

 $T_A=25^{\circ}C$ unless otherwise specified.

Parameter	Symbol	Condition		Min.	Max.	Unit	
Collector-Base Breakdown Voltage	V _{СВО}	I _C = -10 μΑ, I _E = 0		BC856W	-80	-	V
				BC857W	-50	-	
Voltage				BS858W	-30	-	
Collector-Emitter Breakdown Voltage	Vceo	I _C = -10 mA, I _B = 0		BC856W	-65	-	
				BC857W	-45	-	V
				BS858W	-30	-	
Collector-Base Breakdown Voltage	Vebo	I _E = -1 μA, I _C = 0		-5	-	V	
DC Current Gain	h _{FE}	V _{CE} =-5V , I _C =-2mA	BC856AW~BC858AW		125	250	
			BC856BW~BC858BW		220	475	
			BC857CW, BC858CW		420	800	
Collector Cut-off Current	Ісво	$V_{CB} = -30 \text{ V}, \text{ I}_{E} = 0$		-	-15	nA	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	I _C = -100 mA, I _B = -5 mA		-	-0.65	V	
Base-Emitter Saturation Voltage	V _{BE} (sat)	I _C = -100 mA, I _B = -5 mA		-	-1.1	V	
Transition Frequency	f⊤	V _{CE} = -5 V, I _C = -10 mA, f = 100 MHz		100	-	MHz	
Collector Capacitance	C _{ob}	V _{CB} = -10 V, f = 1 MHz		-	4.5	pF	



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TYPICAL CHARACTERISTICS

Fig 1. Static Characteristic

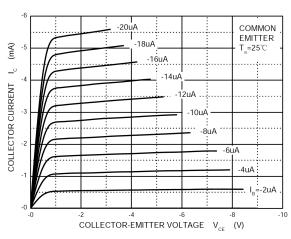
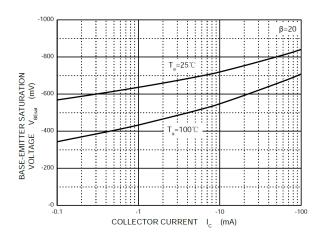
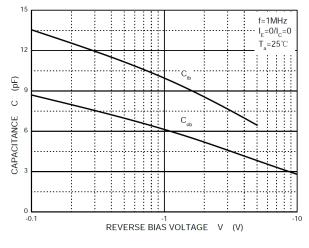


Fig 3. V_{BE (sat)} - I_C







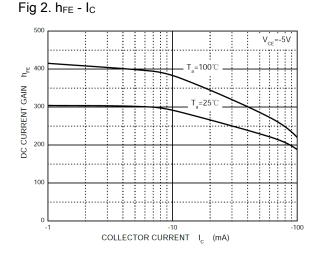
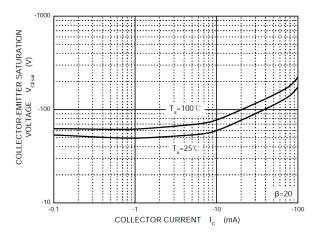
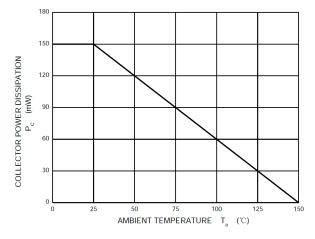


Fig 4. V_{CE (sat)} - I_C





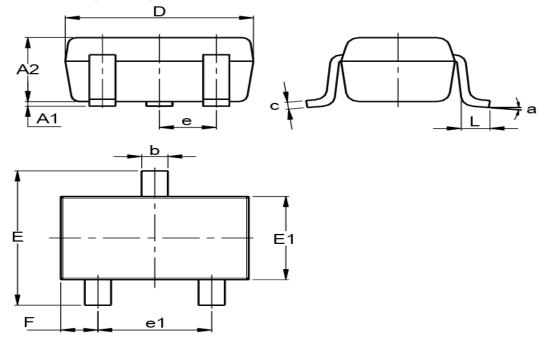


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PACKAGE INFORMATION

Dimension in SOT-323 (Unit: mm)



Currence al	Millimeter		
Symbol	Min.	Max.	
A1	0.000	0.100	
A2	0.800	1.000	
b	0.200	0.400	
с	0.080	0.180	
D	1.000	2.220	
E	2.000	2.450	
E1	1.150	1.350	
е	0.650 TYP.		
e1	1.200	1.400	
F	0.250	0.475	
L	0.250	0.460	
а	0°	8°	



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